



MCH3375 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)1}=227m\Omega$ (typ.)
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-1.6	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-6.4	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² x0.8mm)	0.8	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

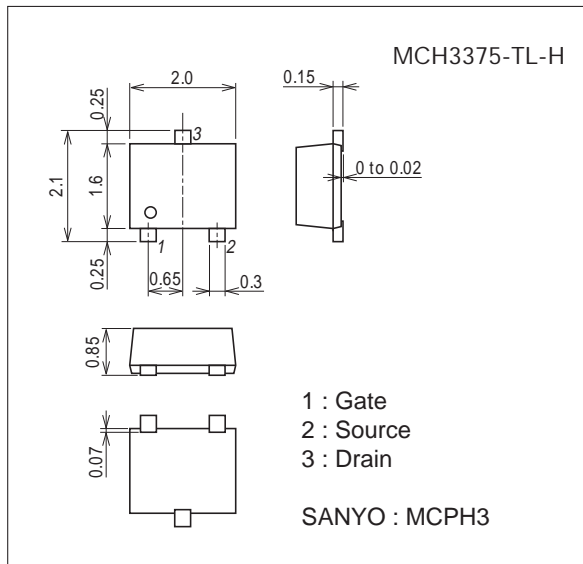
This product is designed to "ESD immunity < 200V**", so please take care when handling.

* Machine Model

Package Dimensions

unit : mm (typ)

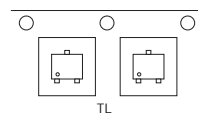
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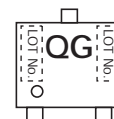
Product & Package Information

- Package : MCPH3
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

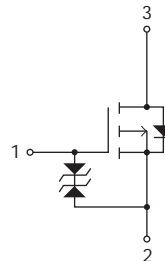
Packing Type: TL



Marking



Electrical Connection

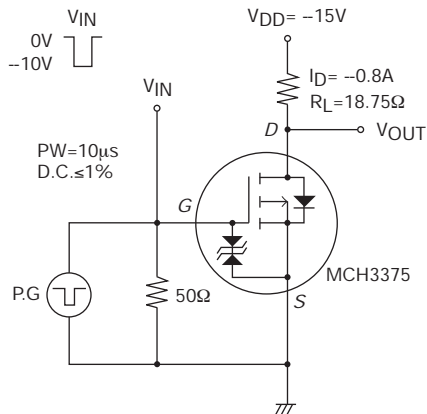


MCH3375

Electrical Characteristics at Ta=25°C

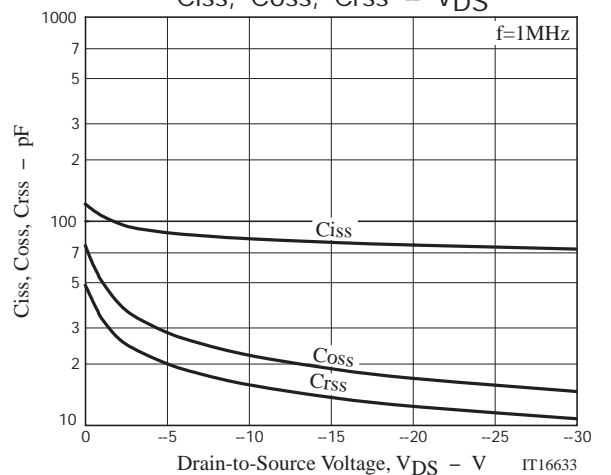
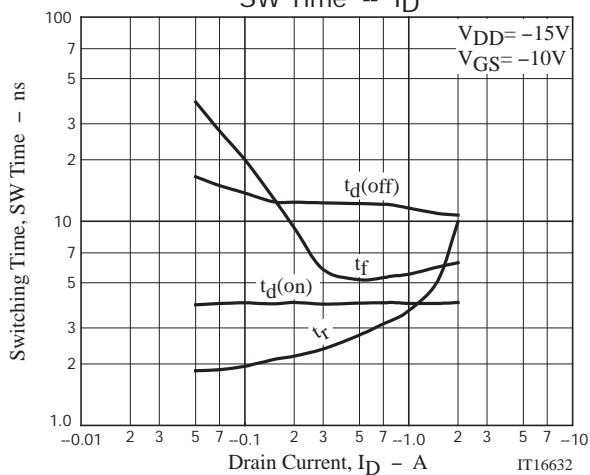
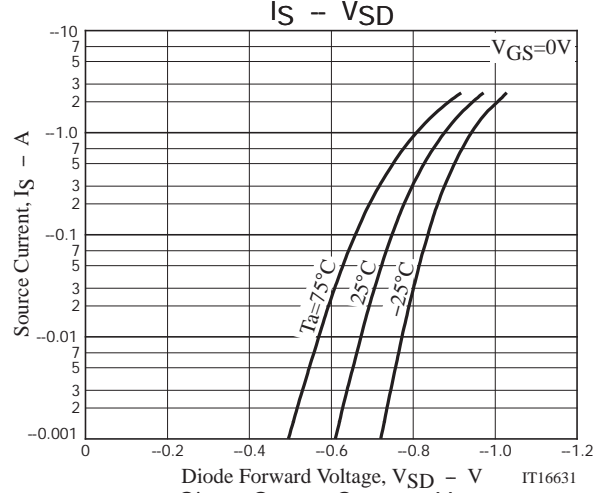
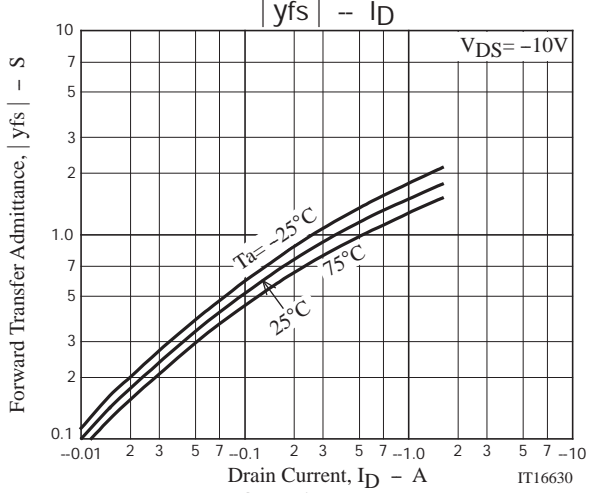
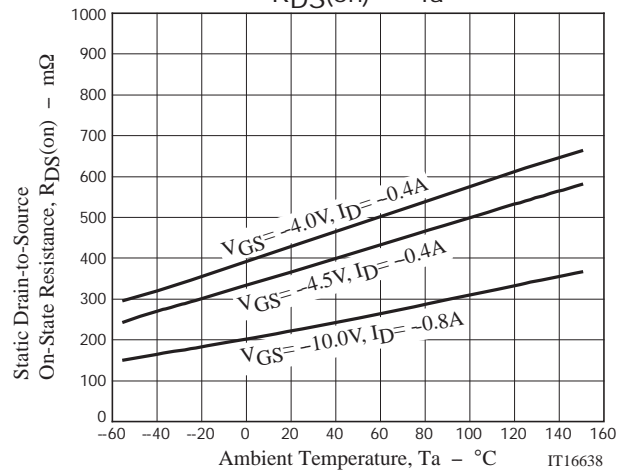
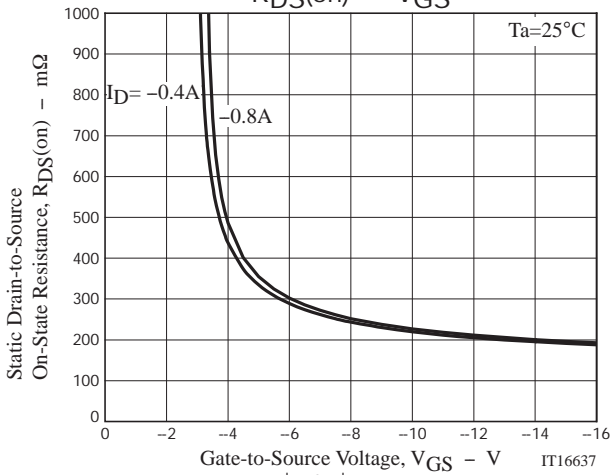
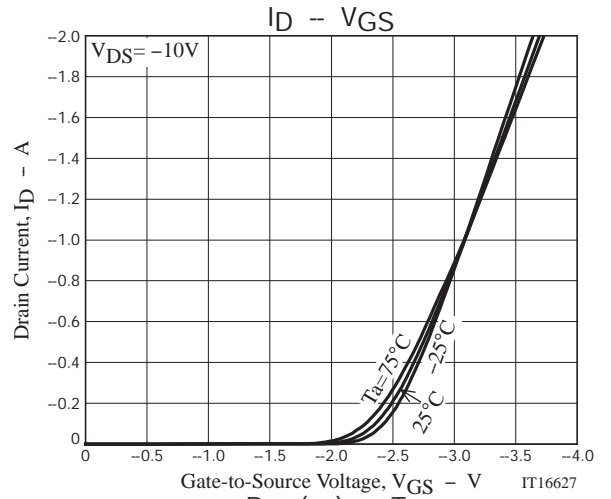
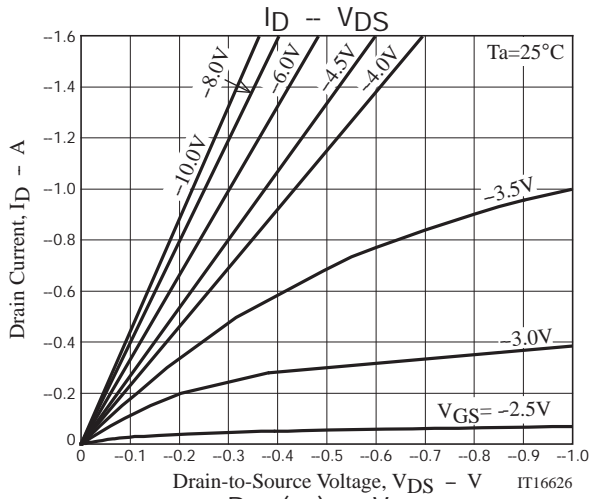
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0V	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-0.8A		1.3		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-0.8A, V _{GS} =-10V		227	295	mΩ
	R _{DS(on)2}	I _D =-0.4A, V _{GS} =-4.5V		374	523	mΩ
	R _{DS(on)3}	I _D =-0.4A, V _{GS} =-4V		435	609	mΩ
Input Capacitance	C _{iss}			82		pF
Output Capacitance	C _{oss}	V _{DS} =-10V, f=1MHz		22		pF
Reverse Transfer Capacitance	C _{rss}			16		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		4.0		ns
Rise Time	t _r			3.3		ns
Turn-OFF Delay Time	t _{d(off)}			12		ns
Fall Time	t _f			5.4		ns
Total Gate Charge	Q _g				2.2	
Gate-to-Source Charge	Q _{gs}	V _{DS} =-15V, V _{GS} =-10V, I _D =-1.6A		0.36		nC
Gate-to-Drain "Miller" Charge	Q _{gd}			0.49		nC
Diode Forward Voltage	V _{SD}		I _S =-1.6A, V _{GS} =0V		-0.9	-1.5

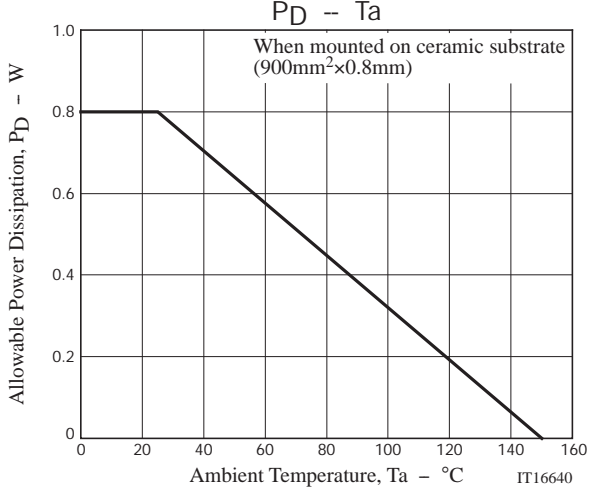
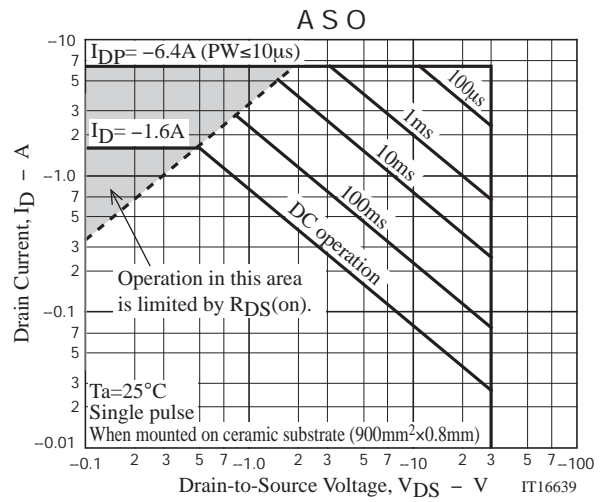
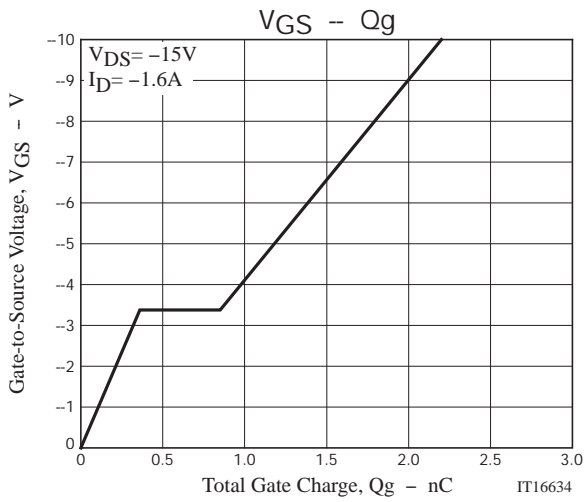
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
MCH3375-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free





Note on usage : Since the MCH3375 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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